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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT240AF,TC74VHCT240AFW,TC74VHCT240AFT,TC74VHCT240AFK TC74VHCT244AF,TC74VHCT244AFW,TC74VHCT244AFT,TC74VHCT244AFK

Octal Bus Buffer

TC74VHCT240AF/AFW/AFT/AFK Inverted, 3-State Outputs

TC74VHCT244AF/AFW/AFT/AFK
Non-Inverted, 3-State Outputs

The TC74VHCT240A and 244A are advanced high speed CMOS OCTAL BUS BUFFFERs fabricated with silicon gate C2MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCT240A is an inverting 3-state buffer having two active-low output enables. The TC74VHCT244A is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

The input voltage are compatible with TTL output voltage. These devices may be used as a level converter for interfacing $3.3~\rm V$ to $5~\rm V$ system.

Input protection and output circuit ensure that 0 to 5.5~V can be applied to the input and output $^{(Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

Features

- High speed: $t_{pd} = 6.1$ ns (typ.) at $V_{CC} = 5$ V
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25^{\circ}C$
- Compatible with TTL outputs: VIL = 0.8 V (max)VIH = 2.0 V (min)
- · Power down protection is provided on all inputs and outputs
- Balanced propagation delays: t_pLH ≃ t_pHL
- Low noise: VOLP = 1.0 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 240/244 type.

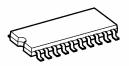
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.) Note: xxxFW (JEDEC SOP) is not available in Japan.

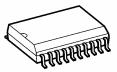


TC74VHCT240AF, TC74VHCT244AF

SOP20-P-300-1.27A



SOP20-P-300-1.27 TC74VHCT240AFW, TC74VHCT244AFW



SOL20-P-300-1.27 TC74VHCT240AFT, TC74VHCT244AFT



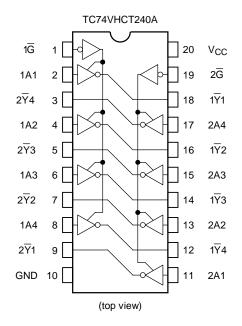
TSSOP20-P-0044-0.65A TC74VHCT240AFK, TC74VHCT244AFK

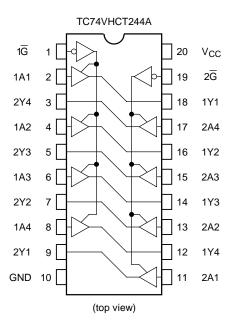


VSSOP20-P-0030-0.50

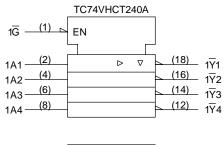


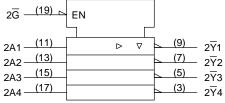
Pin Assignment

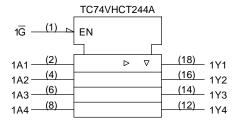


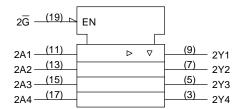


IEC Logic Symbol









Truth Table

Inp	uts	Outputs				
G	An	Yn	\overline{Y}_n			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance

Yn: TC74VHCT244A \overline{Y}_{n} : TC74VHCT240A



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	−0.5 to 7.0	V	
DC input voltage	V _{IN}	-0.5 to 7.0	V	
DC output voltage	V	-0.5 to 7.0 (Note 2)	V	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	lok	±20 (Note 4)	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	Icc	±75	mA	
Power dissipation	PD	180	mW	
Storage temperature	T _{stg}	–65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in off-state

Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	Vout	0 to 5.5 (Note 2)	V
	VOU1	0 to V _{CC} (Note 3)	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 20	ns/V

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Output in off-state

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
	-,				Min	Тур.	Max	Min	Max		
High-level input voltage	VIH	_		4.5 to 5.5	2.0	_		2.0		V	
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	_	0.8	_	0.8	V	
High-level output	V	V _{IN}	$I_{OH} = -50 \mu A$	4.5	4.40	4.50	_	4.40	_	٧	
voltage	Voн	= V _{IH} or V _{IL}	$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_		
Low-level output	Low-level output VOL	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.10	_	0.10	V	
			I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44		
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	_	_	±0.25	_	±2.50	μА	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μА	
	Icc	$V_{IN} = V_{C}$	V _{IN} = V _{CC} or GND		_	_	4.0	_	40.0	μΑ	
Quiescent supply current	Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.50	mA	
Output leakage current	I _{OPD}	V _{OUT} = 5.5 V		0		_	0.5	_	5.0	μА	



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
	, , , ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max		
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	15	_	5.6	7.8	1.0	9.0	ns	
(TC74VHCT240A)	t _{pHL}		0.0 = 0.0	50	_	6.1	8.8	1.0	10.0		
Propagation delay time	t _{pLH}		50.05	15		5.4	7.4	1.0	8.5		
(TC74VHCT244A)	t _{pHL}	_		5.0 ± 0.5	50	_	5.9	8.4	1.0	9.5	ns
3-state output enable	3-state output enable tpZL	$R_L = 1 \text{ k}\Omega$	5.0 ± 0.5	15	_	7.7	10.4	1.0	12.0	ns	
time	^t pZH			50	-	8.2	11.4	1.0	13.0	115	
3-state output disable	t _{pLZ}	$R_L = 1 \text{ kO}$	$R_{I} = 1 k\Omega$	5.0 ± 0.5	50		8.8	11.4	1.0	13.0	ns
time	t _{pHZ}										
Output to output skew	t _{osLH}	(Note 1)	5.0 ± 0.5	50	_	_	1.0	_	1.0	ns	
Output to output skew	t _{osHL}	(14010-1)	0.0 ± 0.0	00			1.0		1.0	110	
Input capacitance	C _{IN}	_			_	4	10	_	10	pF	
Output capacitance	C _{OUT}	_			_	9	_	_	_	pF	
Power dissipation capacitance (Note 2)		TC74VHCT240A		_	19	_	_	_	~F		
	C_{PD}	TC74VHCT244A			_	18	_	_		pF	

Note 1: Parameter guaranteed by design.

$$t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \ t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

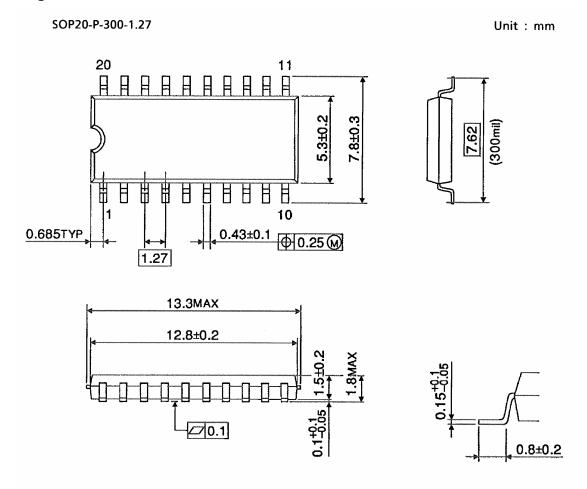
Noise Characteristics (input: $t_r = t_f = 3$ ns) (Note)

Characteristics	Cumbal	Test Condition		Ta =	Ta = 25°C	
Characteristics	Symbol		V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _I = 50 pF	5.0	0.8	1.0	V
		Ο[= 50 με		(0.9)	(1.1)	
Quiet output minimum dynamic V _{OL}	V _{OLV}	$C_1 = 50 \text{ pF}$	5.0	-0.8	-1.0	V
		OL = 00 pi		(-0.9)	(-1.1)	
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	2.0	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	0.8	٧

Note: The value in () only applies to JEDEC SOP (FW) devices.

Weight: 0.22 g (typ.)

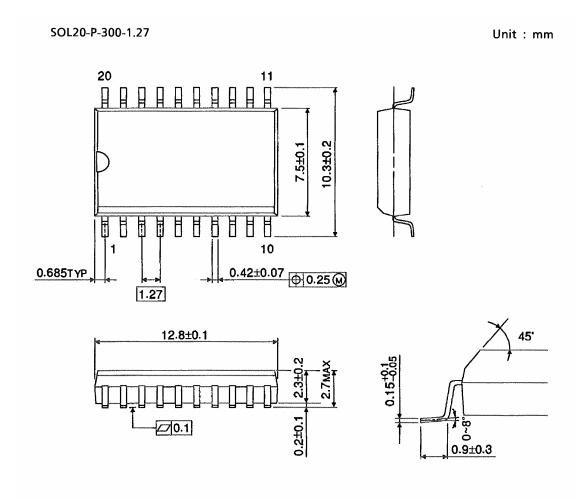




Weight: 0.22 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

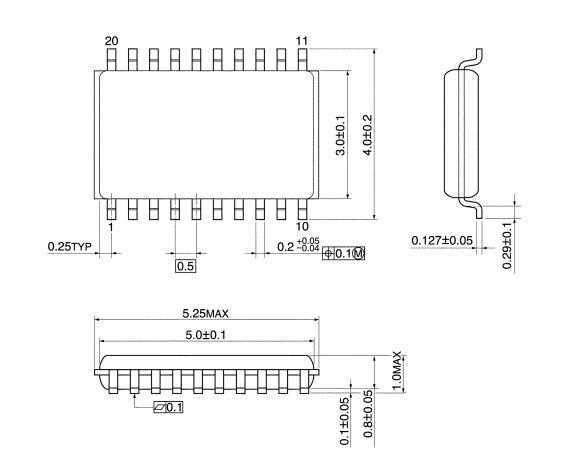


TSSOP20-P-0044-0.65A Unit: mm 6.4±0.2 $0.22\substack{+0.09 \\ -0.06}$ 0.65 0.325TYP **⊕**0.13**M** 6.9MAX 6.5±0.1 1.2MAX 0.15 +0.03 0~10 1.0±0.05 0.1±0.05 S Ø.1|S (0.5)

Weight: 0.08 g (typ.)

0.45~0.75

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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